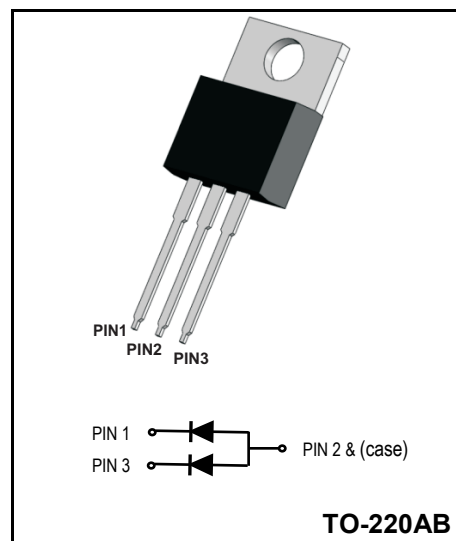


High Efficiency Rectifiers
Reverse Voltage - 800V
Forward Current - 20A
FEATURES

- Glass passivated chip junctions
- High Speed recovery time for switching mode application
- High Forward Surge Capability
- Low Reverse Current
- Lead free in compliance with EU RoHS 2011/65/EU directive


MECHANICAL DATA

- Circuit figure: Common Anode
- Leads: Solderable per mil-std-202, Method 208
- Polarity: as marked
- Mounting torque: 5 in-lbs maximum
- Terminals: Puretin plated
- Weight: TO-220AB 1.85 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (TA=25°C)

RATINGS	SYMBOL	Value	Units
Maximum repetitive reverse voltage	V_{RRM}	800	V
Maximum RMS voltage	V_{RMS}	560	V
Maximum DC blocking voltage	V_{DC}	800	V
Maximum average forward current	I_{AV}	20	A
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load	I_{FSM}	250	A
Typical thermal resistance per diode (Note 1)	$R_{\theta-JC}$	2.5	°C/W
Operation Junction Temperature and Storage Temperature	T_J, T_{STG}	-55 ~ +150	°C
CHARACTERISTICS			
Maximum forward voltage per leg at 10 A	V_F	2.4	V
Maximum average reverse current $T_J=25^{\circ}C$ at rated DC blocking voltage $T_J=125^{\circ}C$	I_R	5 250	μA
Maximum reverse recovery time (Note 2)	T_{RR}	35	nS

Notes: 1. Thermal resistance from junction to case.
2. Test conditions: $I_F=0.5A$, $I_R=1.0A$, $IRR=0.25A$.

Ratings And Characteristic Curves

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

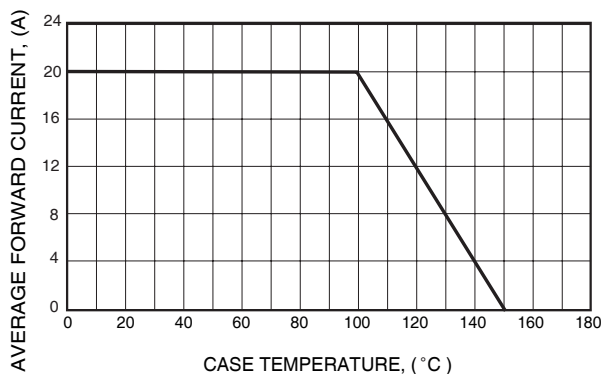


FIG. 3 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

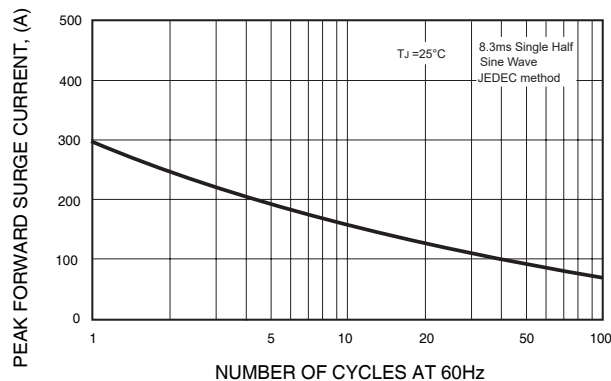


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

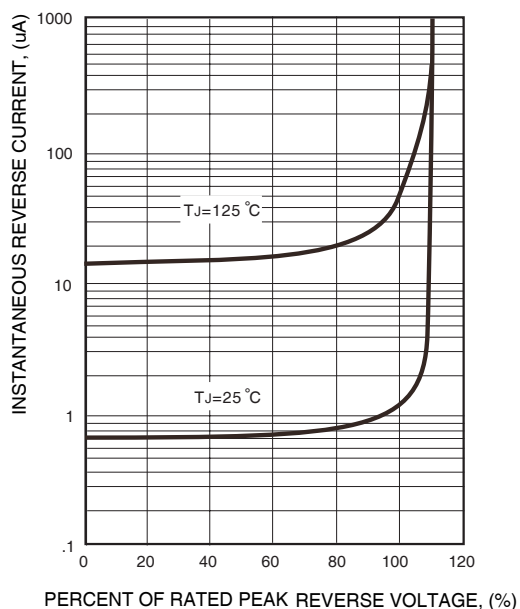


FIG. 2 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

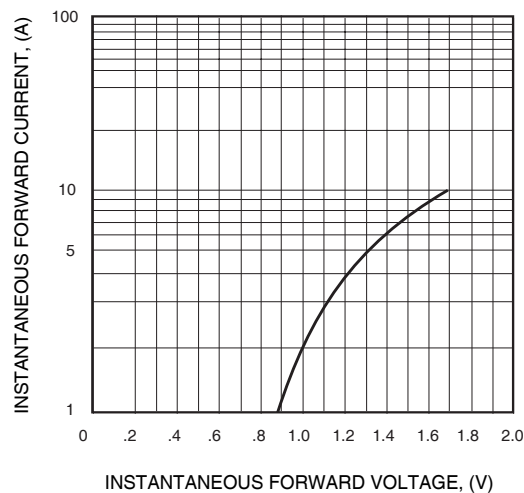
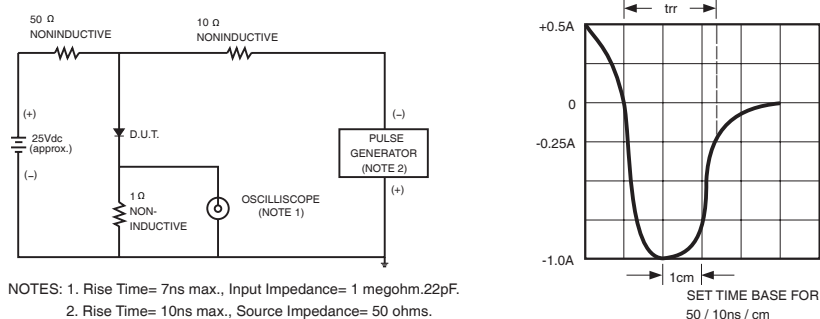


FIG. 6- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



Package outline Dimensions in millimeters

TO-220AB

